

BL8023C

300mA Bi-Direction Relay Driver

DESCRIPTION

BL8023C is a bi-direction relay driver circuit, used to control the magnetic latching relay, with large output capability, ultra-low power consumption. It can be widely used in smart meters and other pulses, level control applications.

BL8023C can provide 300mA typical driving current, which will different according to the relay coil resistance. The input High Level Threshold of BL8023C is 3V; it can compatible with most single chip microcontroller.

BL8023C is available in SOP-8 and DIP-8 packages.

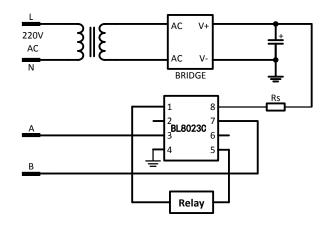
FEATURES

- 5 to 36V input voltage range
- Low Power Consumption (IQ<1uA)
- Input High Level Threshold: 3V, compatible with most single chip microcontroller
- Typical Driving Current: 300mA Rds(on)=12ohm(Vin=12V, PMOSFET+NMOSFET) Rds(on)=10ohm(Vin=30V, PMOSFET+NMOSFET)
- Peak Driving Current: 500mA@Vin=24V
- Environment Temperature: -40°C~85°C
- SOP-8 and DIP-8 packages

APPLICATIONS

Smart Meter

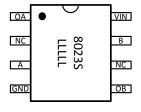
TYPICAL APPLICATION



ORDERING INFORMATION

Part No.	Package	Tape & Reel
BL8023C	SOP-8	2500/Reel

PIN OUT & MARKING



SOP-8/DIP8

8023S: Product Code

LL: Lot No. L: Fab code LL: Date code

ABSOLUTE MAXIMUM RATING

Parameter			Value	
Max Input Voltage			40V	
Max Operating Junction Temperature(Tj)			150°C	
Ambient Temperature(Ta)			-40°C – 125°C	
Package Thermal Resistance	SOP-8	θ_{ja}	128°C / W	
		θ_{jc}	45°C / W	
Storage Temperature(Ts)			-40°C - 150°C	
Lead Temperature & Time			260°C, 10S	

Note: Exceed these limits to damage to the device. Exposure to absolute maximum rating conditions may affect device reliability.

RECOMMENDED WORK CONDITIONS

Parameter	Value	
Input Voltage Range	Max.36V	
Operating Junction Temperature(Tj)	-40°C –85°C	

ELECTRICAL CHARACTERISTICS

(VIN=5V, $T_A=25^{\circ}C$)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
VIN	Input Voltage Range		5		36	V
Iq	Quiescent Current				1	uA
		Vin=12V, R _L =75ohm		12	18	ohm
Rdson Switch Rdson	Switch Delega	Vin=30V, R _L =75ohm		10	16	ohm
	Switch Ruson	Vin=12V, R _L =40ohm		12	20	ohm
		Vin=30V, R _L =40ohm ¹		10	16	ohm
V_{TH}	ON Input High Voltage	Vin=12V		3		V
R _{IN}	Equivalent Input Resistor			500		Kohm
V _{SD}	Fly-Wheel Diode Forward Voltage	Is=1A		1.2	2	V
T _R	Rise Time	VIN=12V, R _L =75ohm		40		ns
T _{D(ON)}	Turn ON Delay Time	VIN=12V, R _L =75ohm		60		ns
T _F	Fall Time	VIN=12V, R _L =75ohm		30		ns
T _{DIOFF)}	Turn OFF Delay Time	VIN=12V, R _L =75ohm		70		ns

Note: 1) This condition is not suitable for SOT23-6 package.

LOGIC FUNCTION TABLE

Input A	Input B	Output OA	Output OB	RELAY RESPONSE
1	0	1	0	ON
0	1	0	1	OFF
0	0	High-impedance	High-impedance	Hold
1	1	High-impedance	High-impedance	Hold

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²⁾ Input rise/fall time must less than 1ms, otherwise maybe destroy the chip.

PIN DESCRIPTION

PIN#	NAME	DESCRIPTION
1	OA	Output A
2, 6	NC	Not connected.
3	Α	Input A
4	GND	Ground.
5	ОВ	Output B
7	В	Input B
8	VIN	Supply input voltage

ELECTRICAL PERFORMANCE

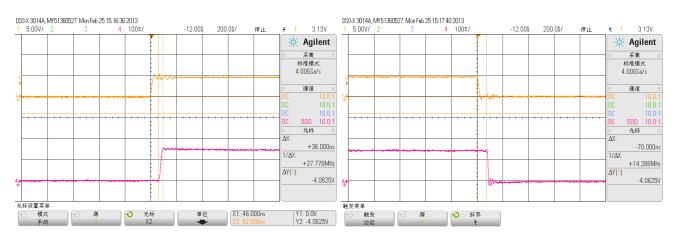
Tested under TA=25°C, unless otherwise specified

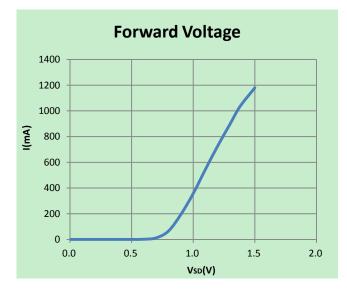
Turn on delay and rise time

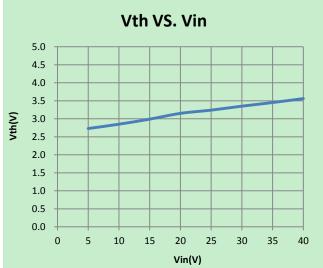
Ch1---Input Ch2---Output

Turn off delay and fall time

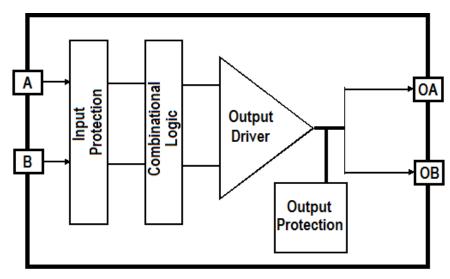
Ch1---Input Ch2---Output







BLOCK DIAGRAM

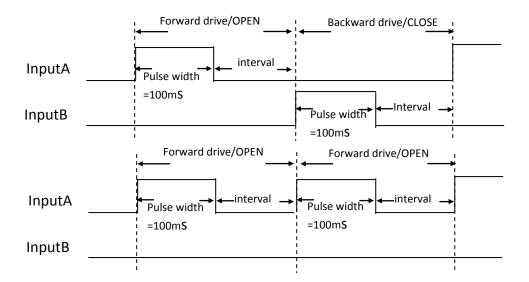


DETAILED DESCRIPTION

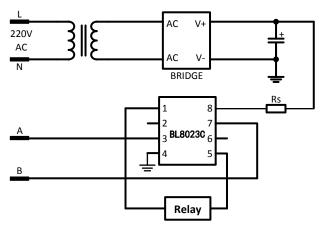
Pulse Triggering

If input is driven by square pulse, connect the inputs to the pulse source directly. Relay will operate as logic table stated (Vin should be less than the power supply voltage, Rs is current-limiting resistor, it can be ignored in the voltage is below 20V, i.e. Rs=0).

The recommended pulse width=100ms. The length of the intervals should be longer than 100ms. These intervals include: intervals between forward drive pulse and next backward drive pulse, intervals between forward drive pulse and next forward drive pulse, intervals between backward drive pulse and next forward drive pulse, intervals between backward drive pulse and next backward drive pulse.



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Pulse triggering application diagram

Relay free-wheel

Relay from ON to OFF, the energy stored in the relay inductor released by the chip's internal body diode and the relay inductor. Until the end of the release of this energy, relay proceeding to the next operation.

PACKAGE OUTLINE

